MH1880 Hall-effect sensor is a temperature stable, stress-resistant sensor. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

MH1880 includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, Advanced DMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries.

This device requires the presence of both south and north polarity magnetic fields for operation. In the presence of a south polarity field of sufficient strength, the device output sensor on, and only switches off when a north polarity field of sufficient strength is present.

MH1880 is rated for operation between the ambient temperatures -40℃ to 125℃ for the K temperature range. The two package styles available provide magnetically optimized solutions for most applications. Package SO is a SOT-23, a miniature low-profile surface-mount package, while package UA is a three-lead ultra mini SIP for through-hole mounting.

Packages is Halogen Free standard and which have been verified by third party lab.

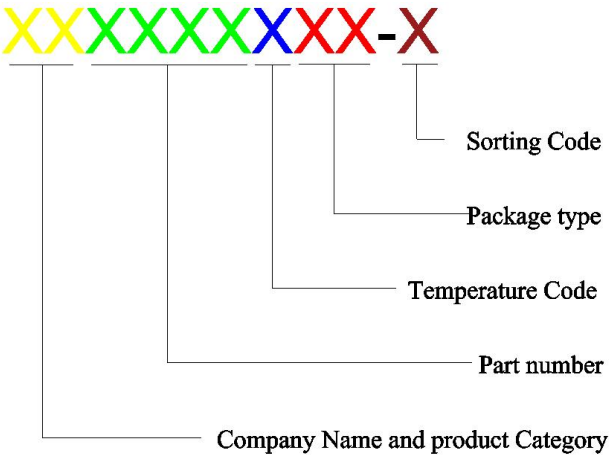
Features and Benefits

- DMOS Hall IC Technology.
- Reverse bias protection on power supply pin.
- Chopper stabilized amplifier stage.
- Optimized for BLDC motor applications.
- Reliable and low shifting on high Temp condition.
- Good ESD Protection.
- 100% tested at 125 ℃ for K.
- Custom sensitivity / Temperature selection are available.
- RoHS compliant 2011/65/EU and Halogen Free

Applications

- High temperature Fan motor
- 3 phase BLDC motor application
- Speed sensing
- Position sensing
- Current sensing
- Revolution counting
- Solid-State Switch
- Linear Position Detection
- Angular Position Detection
- Proximity Detection
- High ESD Capability

Ordering Information



Company Name and Product Category

MH:MST Hall Effect/MP:MST Power IC

Part number

181,182,183,184,185,248,249,276,477,381,381F,381R,382…..

If part # is just 3 digits, the forth digit will be omitted.

Temperature range

E: 85 ℃, I: 105 ℃, K: 125 ℃, L: 150 ℃

Package type

UA:TO-92S,VK:TO-92S(4pin),VF:TO-92S(5pin),SO:SOT-23,
SQ:QFN-3,ST:TSOT-23,SN:SOT-553,SF:SOT-89(5pin),
SS:TSOT-26,SD:DFN-6

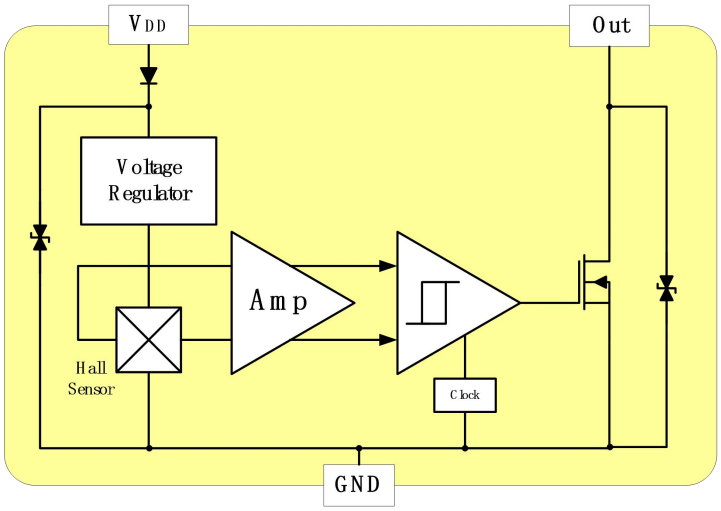
Sorting

α,β,Blank…..

Part No.	Temperature Suffix	Package Type
MH1880KUA	K (-40℃ to + 125℃)	UA (TO-92S)
MH1880KSO	K (-40℃ to + 125℃)	SO (SOT-23)

KUA spec is using in industrial and automotive application. Special Hot Testing is utilized.

Functional Diagram



Absolute Maximum Ratings *At (T_A=25℃)*

Characteristics		Values	Unit
Supply voltage, (V_{DD})		28	V
Output Voltage,(V_{out})		28	V
Reverse voltage, (V_{DD})		-28/-0.3	V
Output current, (I_{SINK})		50	mA
Operating Temperature Range, (Ta)	"K" version	-40 to +125	℃
Storage temperature range, (Ts)		-65 to +150	°C
Maximum Junction Temp,(Tj)		150	°C
Thermal Resistance	(θ_{ja}) UA / SO	206 / 543	℃/W
	(θ_{jc}) UA / SO	148 / 410	℃/W
Package Power Dissipation, (P_D) UA /SO		606 / 230	mW

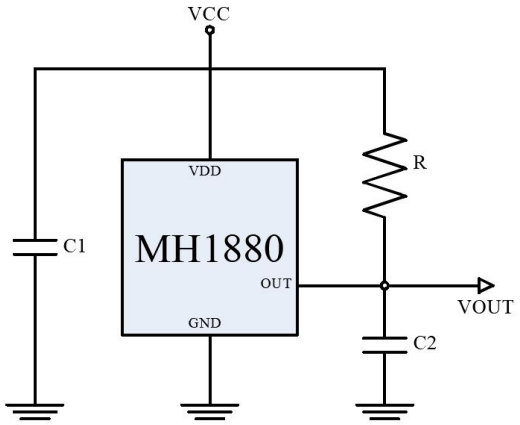
***Note**: Do not apply reverse voltage to* V_{DD} *and* V_{OUT} *Pin, It may be caused for Miss function or damaged device.*

Electrical Specifications

DC Operating Parameters： T_A=25℃, V_{DD}=12V

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage,(V_{DD})	Operating	2.5		18.0	V
Supply Current,(I_{DD})	B<B_{OP}			5.0	mA
Output Saturation Voltage, (V_{sat})	I_{OUT} = 20 mA, B>B_{OP}			400.0	mV
Output Leakage Current, (I_{off})	I_{OFF} B<B_{RP}, V_{OUT} = 12V			10.0	uA
Power-On Time, (T_{PO})	Power-On		0.80		uS
Output Switch Frequency, (F_{SW})		30			kHz
Output Rise Time, (T_R)	R=10kΩ, C2 =20pF		4.0		uS
Output Fall Time, (T_F)	R=10kΩ; C2 =20pF		0.05		uS
Electro-Static Discharge	HBM		7		kV

Typical application circuit



R：10kΩ
C1：10nF
C2：1nF

MH1880 Magnetic Specifications

DC Operating Parameters： T_A *= -40 to 125℃,* V_{DD} *= 2.5 to 18V*

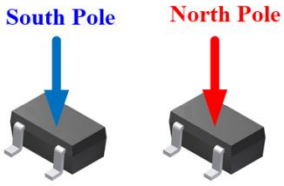
Parameter	Symbol	Test condition	Min	Typ	Max	Unit
Operate Point	B_{OP}	UA(SO)	5(-25)		25(-5)	Gauss
Release Point	B_{RP}	UA(SO)	-25 (5)		-5 (25)	Gauss
Hysteresis	B_{HYS}			30		Gauss

Output Behavior versus Magnetic Pole

DC Operating Parameters： T_A *= -40 to 125℃,* V_{DD} *= 2.5 to 18V*

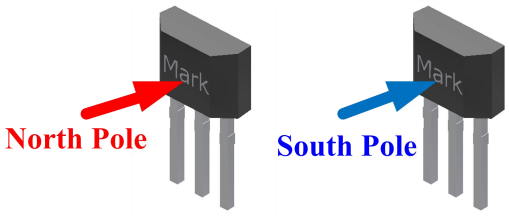
Parameter	Test condition	UA OUT	SO OUT
North pole	B>B_{OP}	Open(Pull-up voltage)	Low(V_{DSON})
South pole	B<B_{RP}	Low(V_{DSON})	Open(Pull-up voltage)

SO package

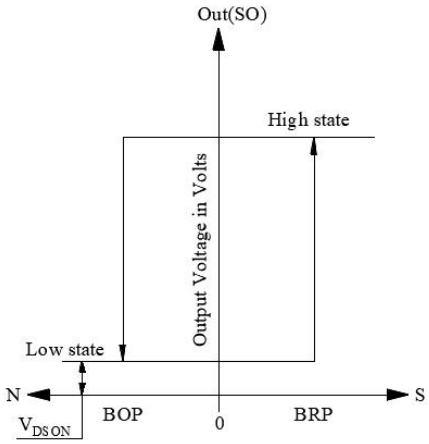


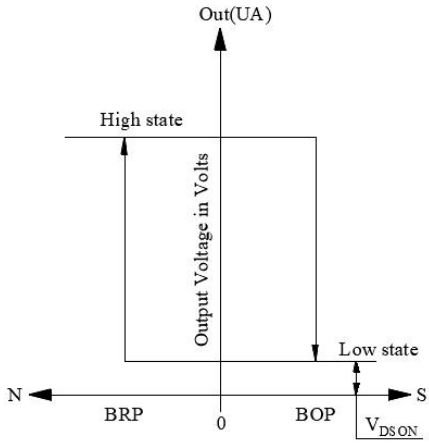
OUT=Hi (Pull-up Voltage) OUT=Low (V_{DSON})

UA package



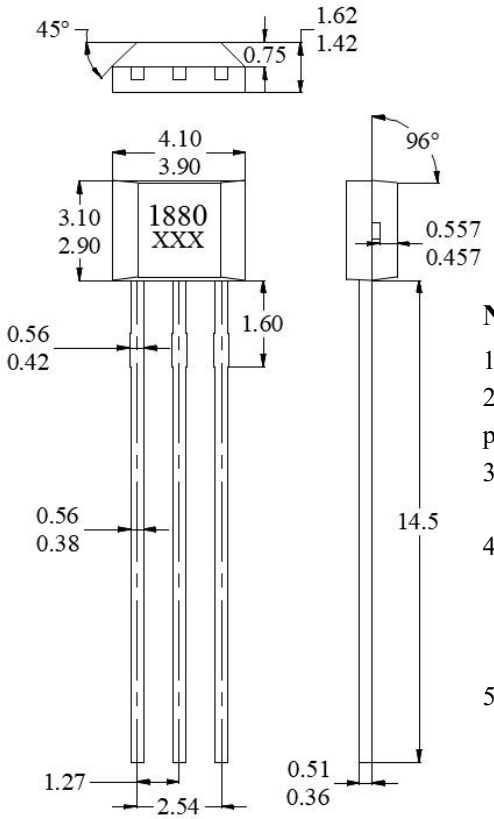
OUT=Hi (Pull-up Voltage) OUT=Low (V_{DSON})





Sensor Location, Package Dimension and Marking

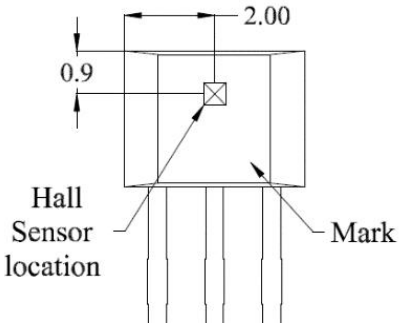
UA Package(TO-92S)



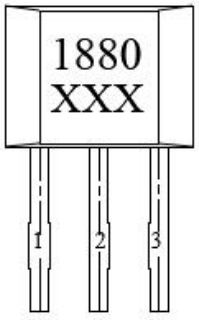
NOTES:

1.Controlling dimension: mm
2.Leads must be free of flash and plating voids
3.Do not bend leads within 1 mm of lead to package interface.
4.PINOUT:
Pin 1 VDD
Pin 2 GND
Pin 3 Output
5. XXX; 1st X=Year; 2nd and 3rd XX=Week

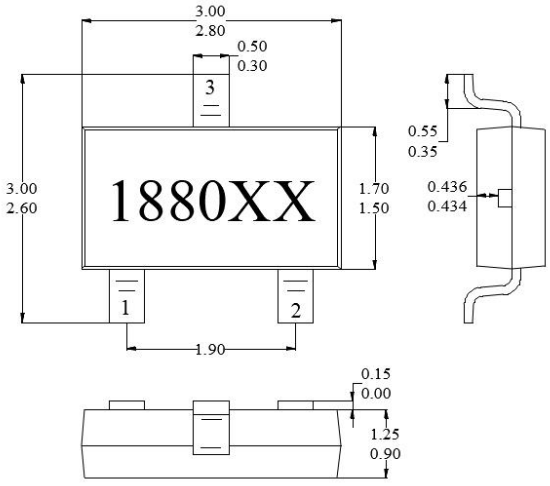
Hall Chip location



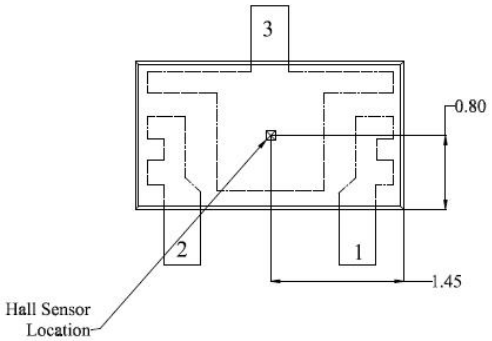
Output Pin Assignment
(Top view)



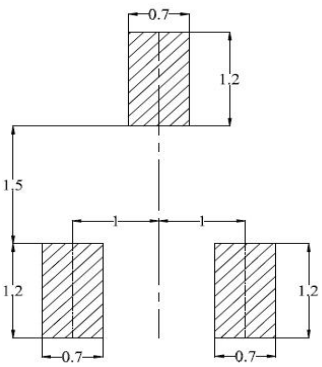
SO Package(SOT-23)
(Top View)



Hall Plate Chip Location
(Bottom view)



(For reference only)Land Pattern



NOTES:

1. PINOUT (See Top View at left :)
   Pin 1 :VDD; Pin 2: Output ; Pin 3 GND
2. Controlling dimension: mm
3. Lead thickness after solder plating will be 0.254mm maximum
4. XX: Date Code, Refer to DC table